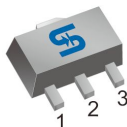


### SOT-89



### Pin Definition:

1. Base
2. Collector
3. Emitter

### PRODUCT SUMMARY

<b>BV<sub>CBO</sub></b>	80V
<b>BV<sub>CEO</sub></b>	50V
<b>I<sub>C</sub></b>	3A
<b>V<sub>CE(SAT)</sub></b>	0.5V @ I <sub>C</sub> / I <sub>B</sub> = 2A / 200mA

### Features

- Low V<sub>CE(SAT)</sub> 0.1 @ I<sub>C</sub> / I<sub>B</sub> = 1A / 50mA (Typ.)
- Complementary part with TSB1424A

### Structure

- Epitaxial Planar Type
- NPN Silicon Transistor

### Ordering Information

Part No.	Package	Packing
TSD2150ACY RM	SOT-89	1Kpcs / 7" Reel

### Absolute Maximum Ratings (T<sub>a</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V <sub>CBO</sub>	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	6	V
Collector Current	DC	3	A
	Pulse	6 (note1)	
Collector Power Dissipation	P <sub>D</sub>	0.6	W
Operating Junction Temperature	T <sub>J</sub>	+150	°C
Operating Junction and Storage Temperature Range	T <sub>STG</sub>	- 55 to +150	°C

**Note:** 1. Single pulse, Pw=10ms, Duty≤50%  
2. When mounted on a 40 x 50 x 0.7mm ceramic board.

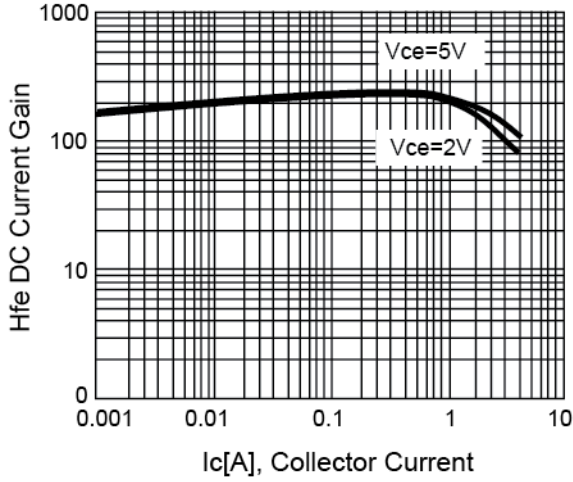
### Electrical Specifications (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	I <sub>C</sub> = 50uA, I <sub>E</sub> = 0	BV <sub>CBO</sub>	80	--	--	V
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 1mA, I <sub>B</sub> = 0	BV <sub>CEO</sub>	50	--	--	V
Emitter-Base Breakdown Voltage	I <sub>E</sub> = 50uA, I <sub>C</sub> = 0	BV <sub>EBO</sub>	6	--	--	V
Collector Cutoff Current	V <sub>CB</sub> = 60V, I <sub>E</sub> = 0	I <sub>CBO</sub>	--	--	0.1	μA
Emitter Cutoff Current	V <sub>EB</sub> = 3V, I <sub>C</sub> = 0	I <sub>EBO</sub>	--	--	0.1	μA
Collector-Emitter Saturation Voltage	I <sub>C</sub> / I <sub>B</sub> = 1A / 50mA	V <sub>CE(SAT)</sub>	--	0.1	0.25	V
	I <sub>C</sub> / I <sub>B</sub> = 2A / 200mA	V <sub>CE(SAT)</sub>	--	0.25	0.5	
Base-Emitter Saturation Voltage	I <sub>C</sub> / I <sub>B</sub> = 2A / 200mA	V <sub>BE(SAT)</sub>	--	--	2	V
DC Current Transfer Ratio	V <sub>CE</sub> = 2V, I <sub>C</sub> = 100mA	h <sub>FE</sub> 1	180	--	--	
	V <sub>CE</sub> = 2V, I <sub>C</sub> = 500mA	h <sub>FE</sub> 2	200	--	400	
	V <sub>CE</sub> = 2V, I <sub>C</sub> = 1A	h <sub>FE</sub> 3	150	--	--	
Transition Frequency	V <sub>CE</sub> = 5V, I <sub>E</sub> = 0.1A, f = 100MHz	f <sub>T</sub>	--	90	--	MHz
Output Capacitance	V <sub>CB</sub> = 10V, f = 1MHz	Cob	--	45	--	pF

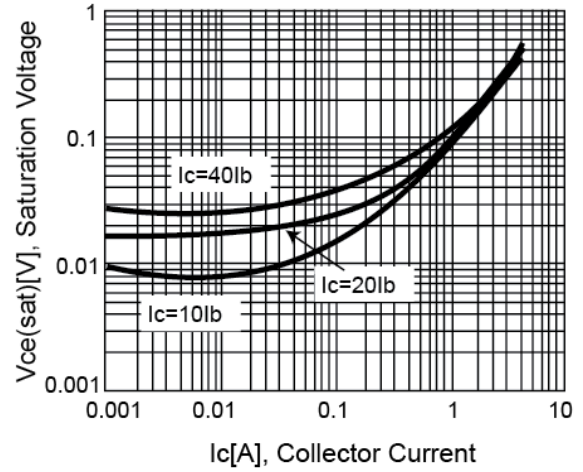
**Note:** Pulse test: pulse width ≤380μs, Duty cycle≤2%

**Electrical Characteristics Curves** ( $T_A=25^{\circ}\text{C}$ , unless otherwise noted)

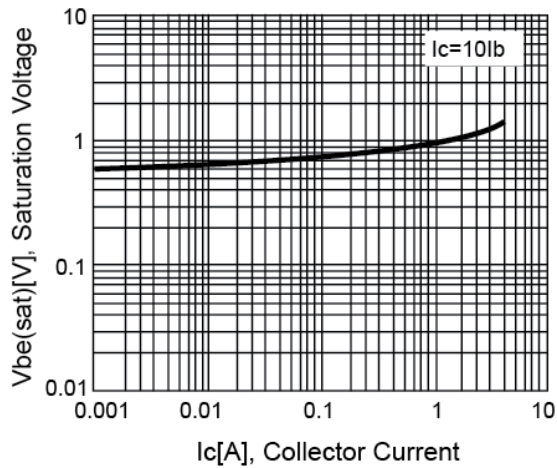
**Figure 1. DC Current Gain**



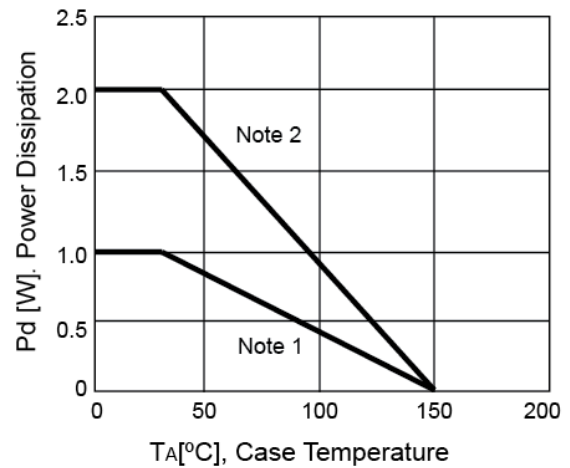
**Figure 2.  $V_{CE(SAT)}$  v.s. Collector Current**



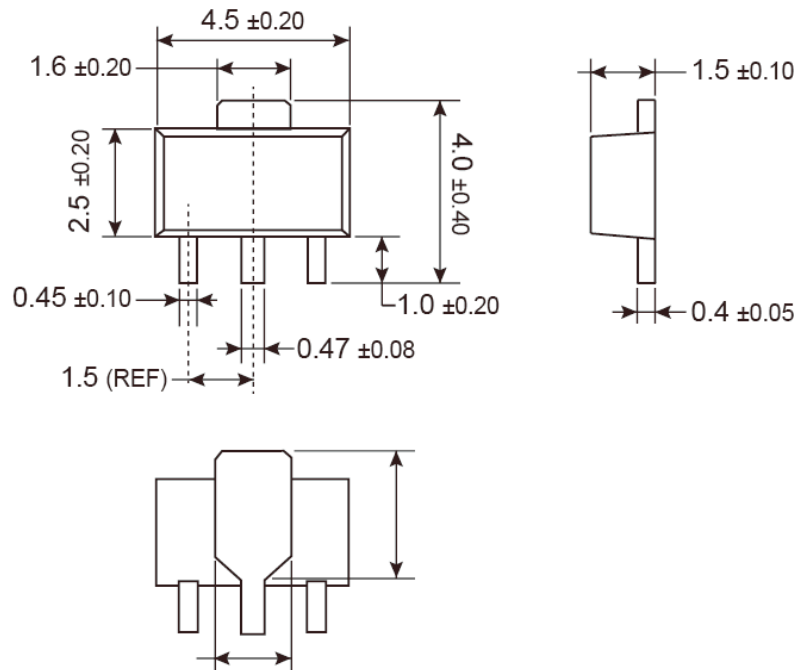
**Figure 3.  $V_{BE(SAT)}$  v.s. Collector Current**



**Figure 4. Power Derating Curve**



**SOT-89 Mechanical Drawing**



Unit: Millimeters

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